



Vishay General Semiconductor

# Ultra Low V<sub>F</sub> Surface Mount Schottky Barrier Rectifiers



The ultra low V<sub>F</sub> Schottky optimized for forward voltage drop with high reverse current trade-off.

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>RRM</sub>	20 V, 30 V			
I <sub>FSM</sub>	30 A			
V <sub>F</sub> at I <sub>F</sub> = 1.0 A	0.30 V			
T <sub>J</sub> max.	125 °C			

## **APPLICATIONS**

Application designed and qualified for hard disk driver where the  $V_{\text{F}}$  performance and size are required. HTIR is not a concern.

### **FEATURES**

Very low profile - typical height of 0.65 mm

Ideal for automated placement

RoHS COMPLIANT HALOGEN

Low forward voltage drop, low power losses

Caution: High reverse leakage

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Halogen-free according to IEC 61249-2-21 definition

### **MECHANICAL DATA**

Case: MicroSMP

Molding compound meets UL 94 V-0 flammability

rating

Base P/N-M3 - halogen-free and RoHS compliant,

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P2U	MSS1P3U	UNIT	
Device marking code		12U	13U		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub> 20 30		V		
Maximum average forward rectified current at T <sub>M</sub> = 110 °C	I <sub>F</sub>	1.0		A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30 0750		Α	
Operating junction temperature range	TJ	- 55 to + 125		°C	
Storage temperature range	T <sub>STG</sub>	- 55 to + 150		°C	

## MSS1P2U & MSS1P3U

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage (1)	$I_F = 0.1 A$ $I_F = 0.5 A$ $I_F = 1.0 A$	T <sub>A</sub> = 25 °C	$V_{F}$	0.23 0.30 0.35	- - 0.40	V
	$I_F = 0.1 A$ $I_F = 0.5 A$ $I_F = 1.0 A$	T <sub>A</sub> = 85 °C		0.16 0.24 0.30	- - 0.35	
Reverse current per diode (2)	V <sub>R</sub> = 30 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 85 °C	I <sub>R</sub>	0.4 12	1.2 30	mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	68	-	pF

#### **Notes**

Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage
conditions. Calculations of T<sub>J</sub> therefore must include forward and reverse power effects.

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P2U	MSS1P3U	UNIT	
Typical thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJM}$	170 30		°C/W	

#### Note

<sup>(1)</sup> Free air, mounted on recommended copper pad area. Thermal resistance  $R_{\theta JA}$  - junction to ambient,  $R_{\theta JM}$  - junction to mount.

ORDERING INFORMATION (Example)						
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUA			BASE QUANTITY	DELIVERY MODE		
MSS1P3U-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel		

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

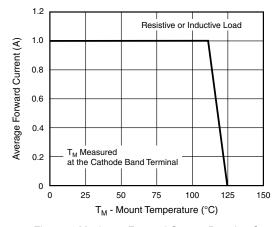


Figure 1. Maximum Forward Current Derating Curve

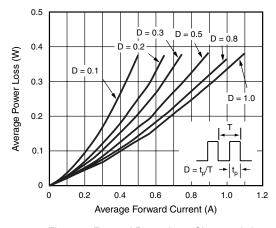


Figure 2. Forward Power Loss Characteristics

 $<sup>^{(1)}</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq 40 \text{ ms}$ 





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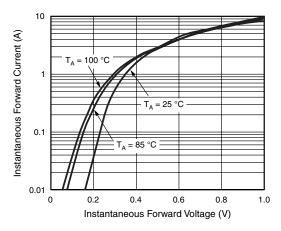


Figure 3. Typical Instantaneous Forward Characteristics

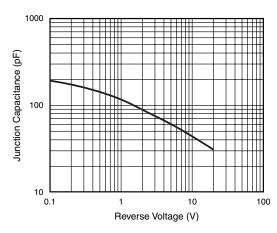


Figure 5. Typical Junction Capacitance

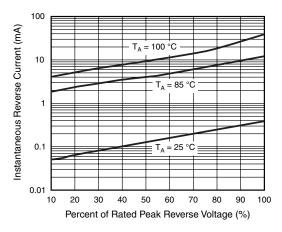


Figure 4. Typical Reverse Characteristics

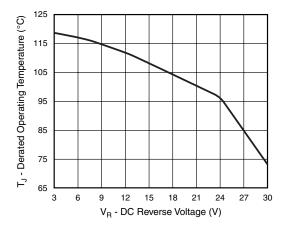


Figure 6. Typical Operating Temperature Derating

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### **MicroSMP** 0.059 (1.50) 0.030 (0.75) Cathode Band 0.043 (1.10) 0.022 (0.55) 0.055 (1.40) 0.047 (1.20) 0.030 (0.75) 0.039 (0.98) 0.031 (0.78) 0.022 (0.55) 0.091 (2.30) 0.083 (2.10) 0.106 (2.70) 0.091 (2.30) **Mounting Pad Layout** 0.079 0.032 (2.00)(0.80) 0.029 (0.73) 0.032 0.043 0.025 (0.63) (1.10) (0.80) 0.011 (0.27) 0.005 (0.12) 0.020 (0.50)



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